

L1N4148WT1G S-L1N4148WT1G

SURFACE MOUNT SWITCHING DIODE

1. FEATURES

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.
- Fast switching speed
- Surface mount package ideally suited for automatic insertion
- For general purpose switching applications
- High conductance



Device	Marking	Shipping
L1N4148WT1G	T4	3000/Tape&Reel
L1N4148WT3G	T4	10000/Tape&Reel

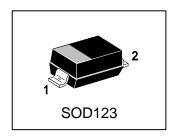
3. MAXIMUM RATINGS(Ta = 25°C)

Parameter	Symbol	Limits	Unit
Non-Repetitive Peak Reverse Voltage	VRM	100	V
Peak Repetitive Reverse Voltage	eak Repetitive Reverse Voltage VRRM		V
Working Peak Reverse Voltage	VRWM	100	
DC Reverse Voltage	VR		
RMS Reverse Voltage	VR(RMS)	53	V
Repetitive Peak Forward Current	IFM	500	mA
Average Rectified Output Current	Ю	200	mA
Non-Repetitive Peak Forward Surge	IFSM		Α
Current			
t=1µs		2	
t=1s		1	

4. THERMAL CHARACTERISTICS

Parameter	Symbol	Limits	Unit
Power Dissipation (Note 1)	PD	425	mW
Thermal Desistance	RΘJA	290	°C/W
Thermal Resistance	ROJC	200	°C/W
Junction and Storage temperature	TJ,Tstg	- 65∼+150	°C

^{1.} Valid provided that terminals are kept at ambient temperature.





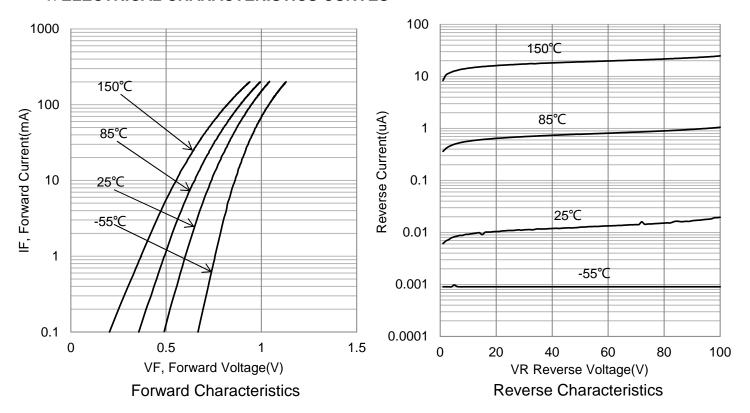


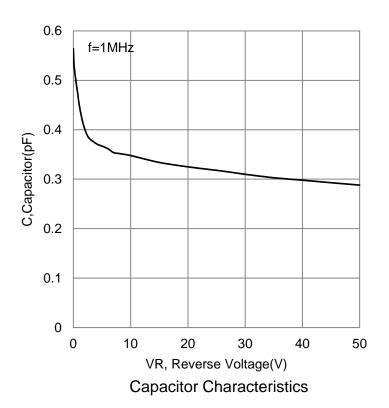
5. ELECTRICAL CHARACTERISTICS (Ta= 25°C)

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage (I(BR)=100µA)	VBR	100	-	-	V
Forward Voltage					
(IF = 1.0 mA)		-	-	715	
(IF = 10 mA)	VF	-	-	855	mV
(IF = 50 mA)		-	-	1000	
(IF = 150 mA)		-	-	1250	
Reverse Voltage Leakage Current					
(VR = 75V)		-	-	2.5	
(VR = 75V,TJ = 150°C)	IR	-	-	50	μΑ
(VR = 25V,TJ = 150°C)		-	-	30	
(VR = 20V)		-	-	0.025	
Diode Capacitance	CD			2.0	, F
(VR = 0V, f = 1.0 MHz)		-	-	2.0	pF
Reverse Recovery Time	trr			4.0	no
(IF=IR=10mA,Irr=0.1×IR,RL =100Ω)	trr	-	-	4.0	ns



6. ELECTRICAL CHARACTERISTICS CURVES







7.OUTLINE AND DIMENSIONS

A1

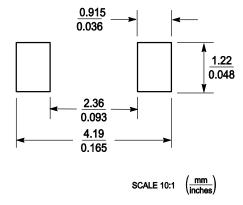
Notes:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.94	1.17	1.35	0.037	0.046	0.053
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.51	0.61	0.71	0.020	0.024	0.028
С			0.15			0.006
D	1.40	1.60	1.80	0.055	0.063	0.071
Е	2.54	2.69	2.84	0.100	0.106	0.112
H _E	3.56	3.68	3.86	0.140	0.145	0.152
L	0.25			0.010		
θ	0°		10°	0°		10°

8.SOLDERING FOOTPRINT

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DISCLAIMER

- Curve guarantee in the specification. The curve of test items with electric parameter is used as quality guarantee. The curve of test items without electric parameter is used as reference only.
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